NSN 5961-00-498-5852

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-498-5852 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -30.0 gate to source voltage all transistor and -30.0 drain to source voltage all transistor **Current Rating Per Characteristic:** -25.00 milliamperes drain cutoff current all transistor and 0.10 milliamperes gate current all transistor **Power Rating Per Characteristic:** 112.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: